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### **MGSF3455XT1**

Preliminary Information

# Low R<sub>DS(on)</sub> Small-Signal MOSFETs Single P-Channel Field Effect Transistors

These miniature surface mount MOSFETs utilize the High Cell Density, HDTMOS process. Low  $r_{DS(on)}$  assures minimal power loss and conserves energy, making this device ideal for use in small power management circuitry. Typical applications are dc-dc converters, power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

- Low r<sub>DS(on)</sub> Provides Higher Efficiency and Extends Battery Life
- Miniature TSOP 6 Surface Mount Package Saves Board Space



#### ON Semiconductor®

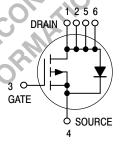
http://onsemi.com

### P-CHANNEL ENHANCEMENT-MODE MOSFET

 $R_{DS(on)} = 80 \text{ m}\Omega \text{ (TYP)}$ 



CASE 318G-02, Style 1 TSOP 6 PLASTIC



### MAXIMUM RATINGS (T<sub>J</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V <sub>DSS</sub>	30	Vdc
Gate-to-Source Voltage — Continuous	V <sub>GS</sub>	± 20	Vdc
Drain Current — Continuous @ T <sub>A</sub> = 255C — Pulsed Drain Current (t <sub>p</sub> 3 10 ms)	I <sub>D</sub> I <sub>DM</sub>	1.45 10	Α
Total Power Dissipation @ T <sub>A</sub> = 255C	P <sub>D</sub>	400	mW
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	– 55 to 150	°C
Thermal Resistance — Junction-to-Ambient	$R_{\theta JA}$	300	°C/W
Maximum Lead Temperature for Soldering Purposes, for 10 seconds	TL	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1

#### **ORDERING INFORMATION**

Device	Reel Size	Tape Width	Quantity
MGSF3455XT1	7″	8 mm embossed tape	3000
MGSF3455XT3	13″	8 mm embossed tape	10,000

#### MGSF3455XT1

### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

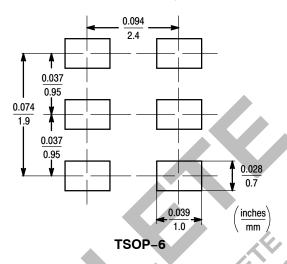
Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS		L	I.	I.	I.	I.
Drain-to-Source Breakdown Voltage ( $V_{GS}$ = 0 Vdc, $I_D$ = 10 $\mu$ A)		V <sub>(BR)DSS</sub>	30	_	_	Vdc
Zero Gate Voltage Drain Current $(V_{DS} = 30 \text{ Vdc}, V_{GS} = 0 \text{ Vdc})$ $(V_{DS} = 30 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}, T_J = 70^{\circ}\text{C})$		I <sub>DSS</sub>			1.0 5.0	μAdc
Gate-Body Leakage Current (V <sub>GS</sub> = :	± 20 Vdc, V <sub>DS</sub> = 0)	I <sub>GSS</sub>	_	_	±100	nAdc
ON CHARACTERISTICS <sup>(1)</sup>		<u> </u>				
Gate Threshold Voltage ( $V_{DS} = V_{GS}$ , $I_D = 250 \mu Adc$ )		V <sub>GS(th)</sub>	1.0	_	_	Vdc
Static Drain-to-Source On-Resistance $(V_{GS} = 10 \text{ Vdc}, I_D = 1.45 \text{ A})$ $(V_{GS} = 4.5 \text{ Vdc}, I_D = 1.2 \text{ A})$		T <sub>DS</sub> (on)		0.080 0.134	0.100 0.190	Ohms
DYNAMIC CHARACTERISTICS					0	
Input Capacitance	(V <sub>DS</sub> = 5.0 V)	C <sub>iss</sub>	_	90	<b>)</b> '-	pF
Output Capacitance	(V <sub>DS</sub> = 5.0 V)	C <sub>oss</sub>	_	50	_	
Transfer Capacitance	(V <sub>DG</sub> = 5.0 V)	C <sub>rss</sub>	/ /	10	_	
SWITCHING CHARACTERISTICS <sup>(2)</sup>			V 73	.0		
Turn-On Delay Time		t <sub>d(on)</sub>	<b>℃</b> ⊖,	10	20	ns
Rise Time	$(V_{DD} = 15 \text{ Vdc}, I_D = 1.0 \text{ A},$	<b>t</b> r	0-1	15	30	
Turn-Off Delay Time	$V_{GEN} = 10 \text{ V}, R_L = 10 \Omega$	t <sub>d(off)</sub>		20	35	
Fall Time		t <sub>f</sub>	(O)	10	20	
Gate Charge	(5)	$Q_{T}$	_	3000	_	рC
SOURCE-DRAIN DIODE CHARACTE	RISTICS					
Continuous Current	10,711	Is	_	_	1.0	Α
Pulsed Current	(7,10)	I <sub>SM</sub>	_	_	5.0	Α
Forward Voltage <sup>(2)</sup>	0 1	V <sub>SD</sub>	_	0.85	_	V

<sup>(1)</sup> Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.
(2) Switching characteristics are independent of operating junction temperature.

#### INFORMATION FOR USING THE TSOP-6 SURFACE MOUNT PACKAGE

#### MINIMUM RECOMMENDED FOOTPRINT FOR SURFACE MOUNTED APPLICATIONS

Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor packages must be the correct size to insure proper solder connection interface between the board and the package. With the correct pad geometry, the packages will self align when subjected to a solder reflow process.



#### TSOP-6 POWER DISSIPATION

The power dissipation of the TSOP–6 is a function of the drain pad size. This can vary from the minimum pad size for soldering to a pad size given for maximum power dissipation. Power dissipation for a surface mount device is determined by  $T_{J(max)}$ , the maximum rated junction temperature of the die,  $R_{\theta JA}$ , the thermal resistance from the device junction to ambient, and the operating temperature,  $T_A$ . Using the values provided on the data sheet for the TSOP–6 package,  $P_D$  can be calculated as follows:

$$P_D = \frac{T_{J(max)} - T_A}{R_{0.1A}}$$

The values for the equation are found in the maximum ratings table on the data sheet. Substituting these values into the equation for an ambient temperature  $T_A$  of 25°C, one can calculate the power dissipation of the device which in this case is 400 milliwatts.

$$P_D = \frac{-150^{\circ}C - 25^{\circ}C}{300^{\circ}C/W} = 400 \text{ milliwatts}$$

The 300°C/W for the TSOP-6 package assumes the use of the recommended footprint on a glass epoxy printed circuit board to achieve a power dissipation of 400 milliwatts. There are other alternatives to achieving higher power dissipation from the TSOP-6 package. Another alternative would be to use a ceramic substrate or an aluminum core board such as Thermal Clad™. Using a board material such as Thermal Clad, an aluminum core board, the power dissipation can be doubled using the same footprint.

#### **SOLDERING PRECAUTIONS**

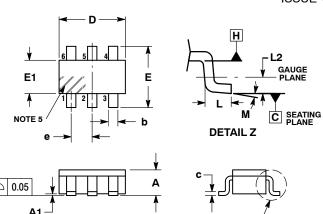
The melting temperature of solder is higher than the rated temperature of the device. When the entire device is heated to a high temperature, failure to complete soldering within a short time could result in device failure. Therefore, the following items should always be observed in order to minimize the thermal stress to which the devices are subjected.

- Always preheat the device.
- The delta temperature between the preheat and soldering should be 100°C or less.\*
- When preheating and soldering, the temperature of the leads and the case must not exceed the maximum temperature ratings as shown on the data sheet. When using infrared heating with the reflow soldering method, the difference shall be a maximum of 10°C.
- The soldering temperature and time shall not exceed 260°C for more than 10 seconds.
- When shifting from preheating to soldering, the maximum temperature gradient shall be 5°C or less.
- After soldering has been completed, the device should be allowed to cool naturally for at least three minutes.
   Gradual cooling should be used as the use of forced cooling will increase the temperature gradient and result in latent failure due to mechanical stress.
- Mechanical stress or shock should not be applied during cooling.
- \* Soldering a device without preheating can cause excessive thermal shock and stress which can result in damage to the device.

#### MGSF3455XT1

#### PACKAGE DIMENSIONS

#### TSOP-6 CASE 318G-02 **ISSUE V**



#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: MILLIMETERS.
  MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM
- LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH,
- PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSIONS D AND E1 ARE DETERMINED AT DATUM H.
  5. PIN ONE INDICATOR MUST BE LOCATED IN THE INDICATED ZONE.

DETAIL Z  MILLIMETERS DIM MIN NOM MAX A 0.90 1.00 1.10 b 0.25 0.38 0.50 c 0.10 0.18 0.26 D 2.20 0.30 0.30 3.10 E1 1.30 1.50 1.70 e 0.08 0.95 1.05 L 0.25 0.40 0.60 L2 0.40 0.60	DETAIL Z    M	DETAIL Z    Mill   Mill   Mod   Max     A   0.90   1.00   1.10     A   0.01   0.06   0.10     b   0.25   0.38   0.50     c   0.10   0.18   0.26     D   2.90   3.00   3.10     E   2.50   2.75   3.00     E   1.30   1.50   1.70     e   0.85   0.98   1.05     L   0.20   0.40   0.60     L   0.20   0.40   0.40     L   0.20   0.40   0.40     L   0.20	¥     →		
A 0.90 1.00 1.10  A 1. 0.01 0.06 0.10  b 0.25 0.38 0.50  c 0.10 0.18 0.26  D 2.20 2.75 3.00  E 2.50 2.75 3.00  E 1.30 1.50 1.70  e 0.85 0.95 1.05  L 0.20 0.40 0.60  L2 0.25 BSC  M 0.9 - 10°  STYLE 1: PIN 1. DRAIN 2. DRAIN 3. GATE 4. SOURCE 5. DRAIN 6. DRAIN 6. DRAIN	DETAIL Z  A 0.90 1.10 0.06 0.10 b 0.25 0.38 0.50 c 0.10 0.18 0.26 D 2.90 3.00 3.10 ET 1.30 1.50 1.70 e 0.85 0.95 1.05 W 0.25 0.98 1.00 ET 1.30 1.50 1.70 e 0.95 0.95 1.05 W 0.95 0.95 1.05 STYLE 1: PIN 1. DRAIN 2. DRAIN 3. GATE 4. SOURCE 5. DRAIN 6. DRAIN 6. DRAIN 6. DRAIN 7. DRAIN 7. DRAIN 7. DRAIN 8. DRAIN 8	DETAIL Z  A 0.90 1.00 1.10 b 0.25 0.38 0.50 c 0.10 0.18 0.28 D 2.90 3.00 3.10 ET 1.30 1.50 1.70 e 0.85 0.98 1.05 L2 0.25 BSC M 0.0 0.25 BSC STYLE 1: PIN 1. DRAIN 2. DRAIN 3. GATE 4. SOURCE 5. DRAIN 6.		MILLIMETERS	
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